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REVISION HISTORY

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SPECIFICATIONS

DUAL SUPPLY

 V_{DD} = +5 V ± 10%, V_{SS} = -5 V ± 10%, GND = 0 V. All specifications -40°C to +85°C, unless otherwise noted.

Table 2.

	B Version ¹				
Parameter	+25°C	-40°C to +85°C	Unit	Test Conditions/Comments	
ANALOG SWITCH					
Analog Signal Range		Vss to VDD	V	$V_{DD} = +4.5 \text{ V}, \text{V}_{SS} = -4.5 \text{ V}$	
On Resistance (Ron)	4		Ωtyp	$V_{s} = \pm 4.5 \text{ V}, I_{Ds} = -10 \text{ mA}; \text{ see Figure 15}$	
	6.5	8.5	Ωmax		
Ron Match Between Channels (ΔRon)	0.7		Ωtyp	$V_{s} = \pm 4.5 \text{ V}, I_{Ds} = -10 \text{ mA}$	
	1.1	1.35	Ωmax		
On-Resistance Flatness (R _{FLAT (ON)})	0.7	0.8	Ωtyp	$V_{S} = \pm 3.3 \text{ V}, I_{DS} = -10 \text{ mA}$	
	1.35	1.4	Ωmax		
LEAKAGE CURRENTS				$V_{DD} = +5.5 V, V_{SS} = -5.5 V$	
Source Off Leakage, Is (Off)	±0.01		nA typ	$V_s = \pm 4.5 V$, $V_D = \mp 4.5 V$; see Figure 16	
	±0.25	±1	nA max		
Channel On Leakage, I _D , I _s (On)	±0.01		nA typ	$V_s = V_D = \pm 4.5 V$; see Figure 17	
5, -, - , - , - ,	±0.25	±1	nA max		
DIGITAL INPUTS					
Input High Voltage, V _{INH}		2.4	V min		
Input Low Voltage, VINL		0.8	V max		
Input Current, linl or linh	0.005		μA typ	$V_{IN} = V_{INL} \text{ or } V_{INH}$	
•		±0.1	µA max		
Digital Input Capacitance, C _{IN}	2		pF typ		
DYNAMIC CHARACTERISTICS ²					
ADG619					
t _{on}	80		ns typ	$R_L = 300 \Omega, C_L = 35 pF$	
	120	155	ns max	V _s = 3.3 V; see Figure 18	
toff	45		ns typ	$R_L = 300 \ \Omega, C_L = 35 \ pF$	
	75	90	ns max	Vs = 3.3 V; see Figure 18	
Break-Before-Make Time Delay, t _{BBM}	40		ns typ	$R_L = 300 \ \Omega, C_L = 35 \ pF$	
		10	ns min	$V_{S1} = V_{S2} = 3.3 V$; see Figure 19	
ADG620					
ton	40		ns typ	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	
	65	85	ns max	$V_s = 3.3 V$; see Figure 18	
toff	200		ns typ	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	
	330	400	ns max	$V_s = 3.3 V$; see Figure 18	
Make-Before-Break Time Delay, t _{MBB}	160		ns typ	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	
		10	ns min	$V_s = 0 V$; see Figure 20	
Charge Injection	110		pC typ	$V_s = 0 V$, $R_s = 0 \Omega$, $C_L = 1 nF$; see Figure 21	
Off Isolation	-67		dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure 22	
Channel-to-Channel Crosstalk	-67		dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure 23	
Bandwidth –3 dB	190		MHz typ	$R_L = 50 \Omega$, $C_L = 5 pF$; see Figure 24	
Cs (Off)	25		pF typ	f = 1 MHz	
C _D , C _S (On)	95		pF typ	f = 1 MHz	

	B Version ¹				
Parameter	+25°C	-40°C to +85°C	Unit	Test Conditions/Comments	
POWER REQUIREMENTS				$V_{DD} = +5.5 \text{ V}, V_{SS} = -5.5 \text{ V}$	
I _{DD}	0.001		μA typ	Digital inputs = 0 V or 5.5 V	
		1.0	μA max		
I _{SS}	0.001		µA typ	Digital inputs = 0 V or 5.5 V	
		1.0	µA max		

 1 Temperature range for B version is $-40^\circ C$ to $+85^\circ C.$ 2 Guaranteed by design, not subject to production test.

SINGLE SUPPLY

 V_{DD} = 5 V ± 10%, V_{SS} = 0 V, GND = 0 V. All specifications -40°C to +85°C, unless otherwise noted.

Table 3.

	B Version ¹		_		
Parameter	+25°C	-40°C to +85°C	Unit	Test Conditions/Comments	
ANALOG SWITCH					
Analog Signal Range		0 V to V _{DD}	V	$V_{DD} = 4.5 V, V_{SS} = 0 V$	
On Resistance (R _{ON})	7		Ωtyp	$V_s = 0 V$ to 4.5 V, $I_{Ds} = -10 \text{ mA}$; see Figure 1	
	10	12.5	Ωmax		
Ron Match Between Channels (ΔRon)	0.8		Ω typ	$V_{s} = 0 V$ to 4.5 V, $I_{Ds} = -10 mA$	
	1.1	1.3	Ωmax		
On-Resistance Flatness (R _{FLAT (ON)})	0.5	0.5	Ωtyp	$V_s = 1.5 V$ to 3.3 V, $I_{Ds} = -10 mA$	
		1.2	Ωmax		
LEAKAGE CURRENTS				$V_{DD} = 5.5 V$	
Source Off Leakage, I _s (Off)	±0.01		nA typ	$V_{\rm S} = 1 \text{V}/4.5 \text{V}, V_{\rm D} = 4.5 \text{V}/1 \text{V};$ see Figure 16	
	±0.25	±1	nA max	, , , , ,	
Channel On Leakage, I _D , I _s (On)	±0.01		nA typ	$V_{s} = V_{D} = 1 V/4.5 V$; see Figure 17	
	±0.25	±1	nA max		
DIGITAL INPUTS	±0.23	<u> </u>	TIT THAN		
Input High Voltage, VINH		2.4	V min		
Input Low Voltage, V _{INL}	0.005	0.8	V max		
Input Current, I _{INL} or I _{INH}	0.005	1	μA typ	$V_{IN} = V_{INL} \text{ or } V_{INH}$	
		±0.1	µA max		
Digital Input Capacitance, CIN	2		pF typ		
DYNAMIC CHARACTERISTICS ²					
ADG619					
ton	120		ns typ	$R_L = 300 \Omega, C_L = 35 pF$	
	220	280	ns max	$V_s = 3.3 V$; see Figure 18	
t _{off}	50		ns typ	$R_L = 300 \Omega$, $C_L = 35 pF$	
	75	110	ns max	Vs = 3.3 V; see Figure 18	
Break-Before-Make Time Delay, tBBM	70		ns typ	$R_L = 300 \Omega, C_L = 35 pF$	
		10	ns min	$V_{S1} = V_{S2} = 3.3 V$; see Figure 19	
ADG620					
ton	50		ns typ	$R_L = 300 \Omega, C_L = 35 pF$	
	85	110	ns max	$V_s = 3.3 V$; see Figure 18	
toff	210		ns typ	$R_L = 300 \Omega, C_L = 35 pF$	
	340	420	ns max	Vs = 3.3 V; see Figure 18	
Make-Before-Break Time Delay, t _{MBB}	170		ns typ	$R_L = 300 \Omega, C_L = 35 pF$	
		10	ns min	$V_s = 3.3 V$; see Figure 20	
Charge Injection	6		pC typ	$V_s = 0 V$, $R_s = 0 \Omega$, $C_L = 1 nF$; see Figure 21	
Off Isolation	-67		dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure	
			7 P	22	
Channel-to-Channel Crosstalk	-67		dB typ	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$; see Figure 23	
Bandwidth –3 dB	190		MHz typ	$R_L = 50 \Omega$, $C_L = 5 pF$; see Figure 24	
C _s (OFF)	25		pF typ	f = 1 MHz	
C _D , C _s (ON)	95		pF typ	f = 1 MHz	
POWER REQUIREMENTS			1	$V_{DD} = 5.5 V$	
IDD	0.001		μA typ	Digital inputs = $0 \text{ V} \text{ or } 5.5 \text{ V}$	
עטי	0.001	1.0			
		1.0	µA max		

¹ Temperature range for B version is -40°C to +85°C. ² Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25^{\circ}C$, unless otherwise noted.

Table 4.

Parameter	Rating
V _{DD} to V _{SS}	13 V
V _{DD} to GND	–0.3 V to +6.5 V
V _{ss} to GND	+0.3 V to -6.5 V
Analog Inputs ¹	$V_{SS} - 0.3 V$ to $V_{DD} + 0.3 V$
Digital Inputs ¹	-0.3 V to V _{DD} + 0.3 V or 30 mA (whichever occurs first)
Peak Current, S or D	100 mA (pulsed at 1 ms, 10% duty cycle maximum)
Continuous Current, S or D	50 mA
Operating Temperature Range	
Industrial (B Version)	-40°C to +85°C
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
MSOP	
θ_{JA} Thermal Impedance	206°C/W
θ_{JC} Thermal Impedance	44°C/W
SOT-23	
θ_{JA} Thermal Impedance	229.6°C/W
θ _{JC} Thermal Impedance	91.99°C/W
Lead Temperature, Soldering (10 sec)	300°C
IR Reflow, Peak Temperature	220°C

¹ Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Only one absolute maximum rating may be applied at a time.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

D 1 S1 2 GND 3 V _{DD} 4	ADG619/ ADG620 TOP VIEW (Not to Scale)	8 S2 7 V _{SS} 6 IN 5 NC	12617-002
N	C = NO CONNEC	Эт	0261
Figu	ıre 2. 8-Lead S((RJ-8)	OT-23	

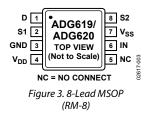


Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	D	Drain Terminal. Can be an input or output.
2	S1	Source Terminal. Can be an input or output.
3	GND	Ground (0 V) Reference.
4	V _{DD}	Most Positive Power Supply.
5	NC	No Connect. Not internally connected.
6	IN	Logic Control Input.
7	Vss	Most Negative Power Supply. This pin is only used in dual-supply applications and should be tied to ground in single-supply applications.
8	S2	Source Terminal. Can be an input or output.

TYPICAL PERFORMANCE CHARACTERISTICS

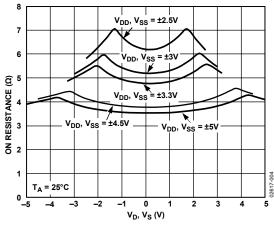


Figure 4. On Resistance vs. V_D, V_s (Dual Supply)

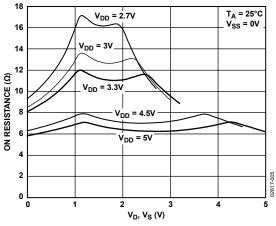


Figure 5. On Resistance vs. V_D, V_s (Single Supply)

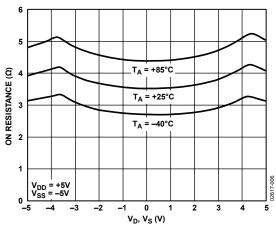


Figure 6. On Resistance vs. V_D, V_S for Different Temperatures (Dual Supply)

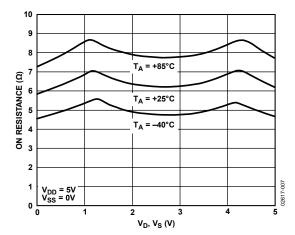


Figure 7. On Resistance vs. V_D, V_S for Different Temperatures (Single Supply)

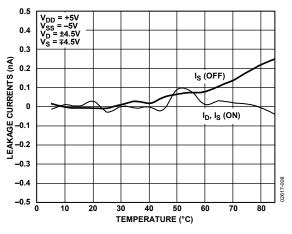


Figure 8. Leakage Currents vs. Temperature (Dual Supply)

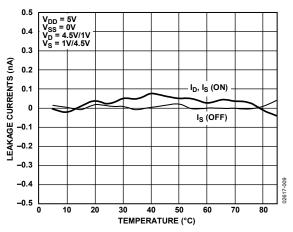


Figure 9. Leakage Currents vs. Temperature (Single Supply)

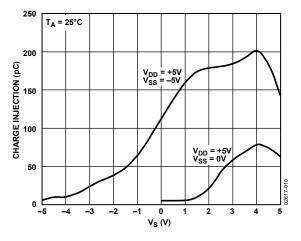


Figure 10. Charge Injection vs. Source Voltage

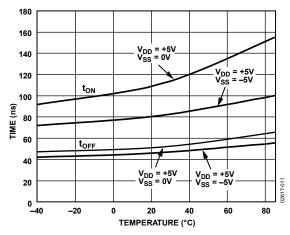
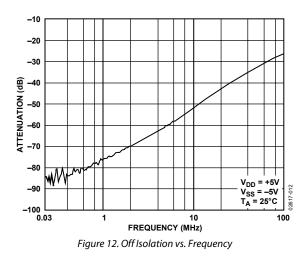
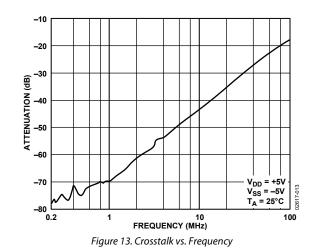


Figure 11. ton/toff Times vs. Temperatures





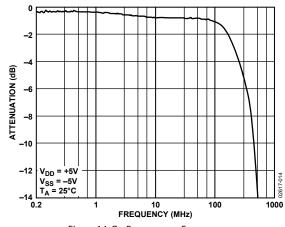


Figure 14. On Response vs. Frequency

TERMINOLOGY

 \mathbf{I}_{DD}

Positive supply current.

Iss Negative supply current.

R_{ON} Ohmic resistance between D and S terminals.

 ΔR_{ON} On resistance match between any two channels.

$R_{\rm FLAT \ (ON)}$

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

Is (Off) Source leakage current with the switch off.

I_D, I_s (On) Channel leakage current with the switch on.

 $\mathbf{V}_{D}, \mathbf{V}_{S}$ Analog voltage on Terminal D and Terminal S.

V_{INL} Maximum input voltage for Logic 0.

 \mathbf{V}_{INH} Minimum input voltage for Logic 1.

I_{INL}, I_{INH} Input current of the digital input.

Cs (Off) Off switch source capacitance. C_D, C_s (On) On switch capacitance.

ton

Delay between applying the digital control input and the output switching on.

toff

Delay between applying the digital control input and the output switching off.

 $\mathbf{t}_{\mathrm{MBB}}$

On time is measured between the 80% points of both switches, when switching from one address state to another.

t_{BBM}

Off time or on time is measured between the 90% points of both switches, when switching from one address state to another.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Crosstalk

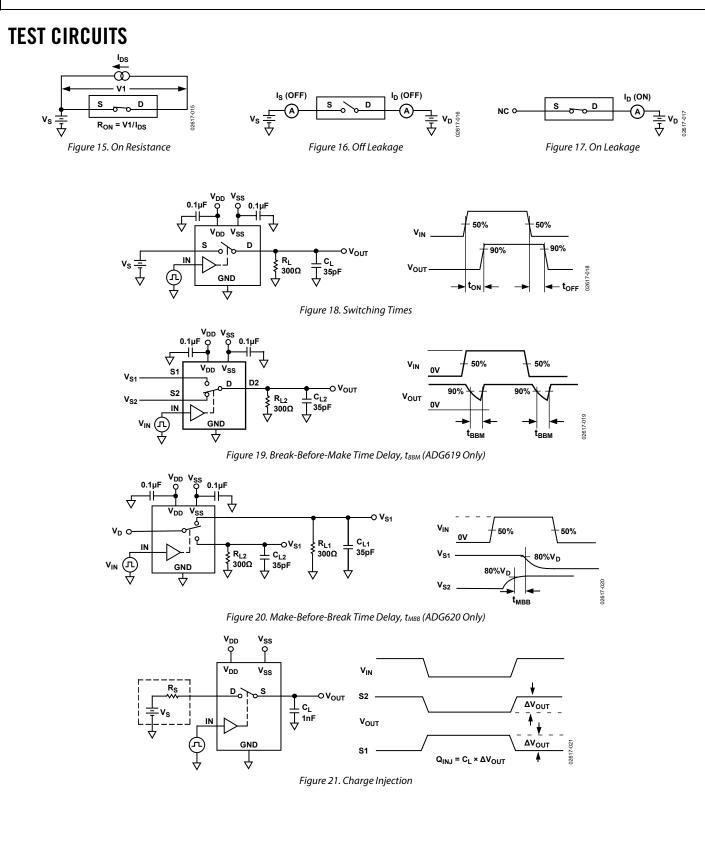
A measure of unwanted signal coupled through from one channel to another as a result of parasitic capacitance.

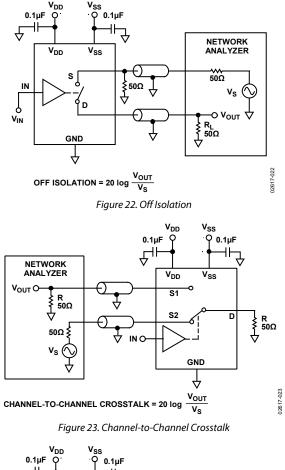
Off Isolation

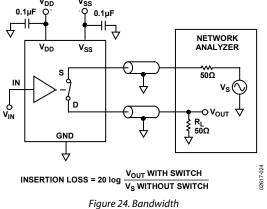
A measure of unwanted signal coupling through an off switch.

Bandwidth The frequency response of the on switch.

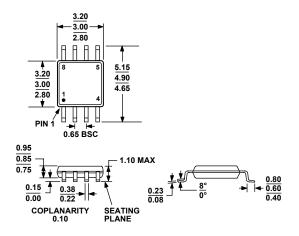
Insertion Loss The loss due to the on resistance of the switch.



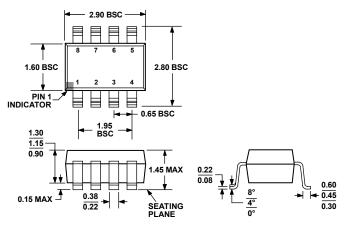




OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-AA Figure 25. 8-Lead Mini Small Outline Package [MSOP] (RM-8) Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-178-BA Figure 26. 8-Lead Small Outline Transistor Package [SOT-23] (RJ-8) Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding ¹
ADG619BRM	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SVB
ADG619BRM-REEL	–40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SVB
ADG619BRM-REEL7	–40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SVB
ADG619BRMZ ²	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SCC
ADG619BRMZ-REEL ²	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SCC
ADG619BRMZ-REEL7 ²	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SCC
ADG619BRT-REEL	-40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SVB
ADG619BRT-REEL7	-40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SVB
ADG619BRT-500RL7	-40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SVB
ADG619BRTZ-REEL ²	-40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SCC
ADG619BRTZ-REEL7 ²	-40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SCC
ADG619BRTZ-500RL7 ²	-40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SCC
ADG620BRM	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SWB
ADG620BRM-REEL	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SWB
ADG620BRM-REEL7	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	SWB
ADG620BRMZ ²	-40°C to +85°C	8-Lead Mini Small Outline Package (MSOP)	RM-8	S21
ADG620BRT-REEL	-40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SWB
ADG620BRT-REEL7	–40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	SWB
ADG620BRTZ-REEL7 ²	–40°C to +85°C	8-Lead Small Outline Transistor Package (SOT-23)	RJ-8	S21

 $^{\rm 1}$ Branding on SOT-23 and MSOP is limited to three characters due to space constraints. $^{\rm 2}$ Z = RoHS Compliant Part.

NOTES

NOTES

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